

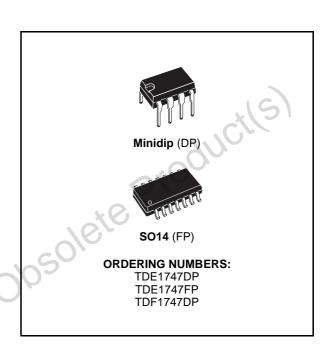
INTERFACE CIRCUIT - RELAY AND LAMP - DRIVER

- OPEN GROUND PROTECTION
- HIGH OUTPUT CURRENT
- ADJUSTABLE SHORT-CIRCUIT PROTEC-TION TO GROUND
- THERMAL PROTECTION WITH HYSTERE-SIS TO AVOID THE INTERMEDIATE OUT-PUT LEVELS
- LARGE SUPPLY VOLTAGE RANGE: + 10 V TO + 45 V
- SHORT-CIRCUIT PROTECTION TO Vcc

DESCRIPTION

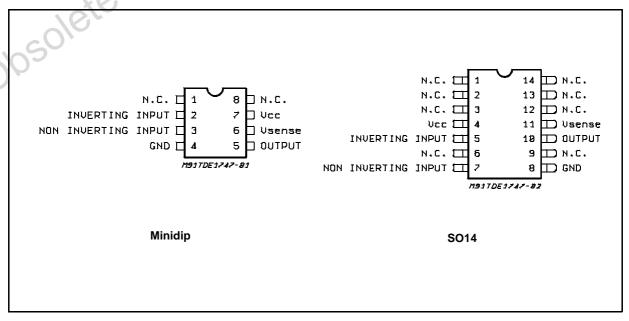
The TDE/TDF1747 is a monolithic comparator designed for high current and high voltage applications, specifically to drive lamps, relays, stepping motors

These device is essentially blow-out proof. Current limiting is available to limit the peak output current to safe values, the adjustment only requires one external resistor. In addition, thermal shut down is provided to keep the I.C. from overheating. If internals dissipation becomes too great, the driver will shut down to prevent excessive heating. TDE1747 has an open ground protection. The output is also protected from short-circuits with the positive power supply.



The device operates over a wide range of supply voltages from standard \pm 15 V operational amplifier supplies down to the single + 12 V or + 24 used for industrial electronic systems.

PIN CONNECTIONS (Top view)



September 2003 1/11

ABSOLUTE MAXIMUM RATINGS

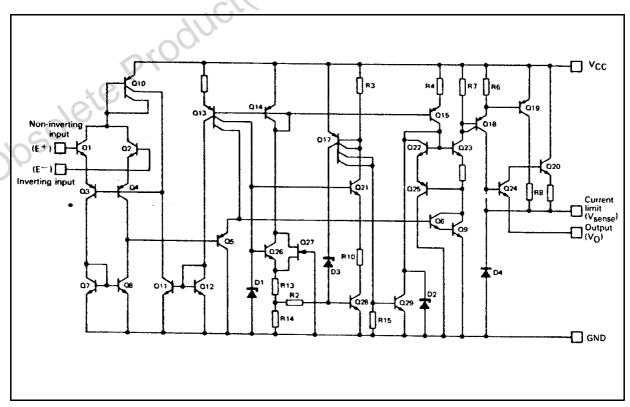
Symbol	Parameter	Value	Unit
V _{CC}	Supply Voltage	50 *	V
V_{ID}	Differantial Input Voltage	50	V
VI	Input Voltage	50	V
Io	Output Current	1	А
P _{tot}	Power Dissipation (T _{amb} = + 25 °C)	Internally Limited	W
T _{stg}	Storage Temperature Range	- 65 to + 150	°C
T _{oper}	Operating Ambient Temperature Range TDE1747 TDF1747	- 25 to + 85 - 40 to + 85	o°C O°C

^{(*) 60}V, t â 10ms

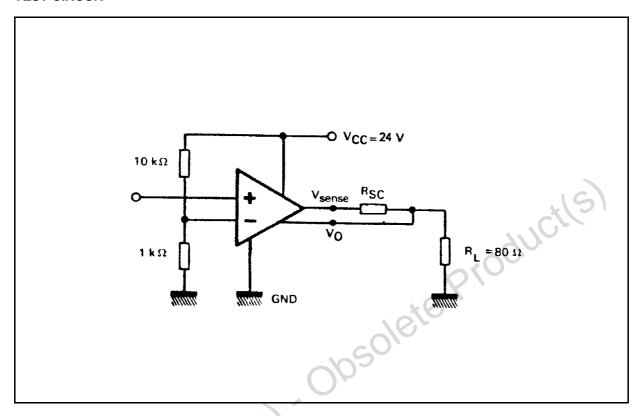
THERMAL CHARACTERISTICS

+				
Symbol	Parameter		Value	Unit
R _{th(j-c)}	Maximum Junction-case Thermal Resistance		50	°C/W
R _{th(j-a)}	Maximum Junction-ambient Thermal Resistance		120	°C/W
R _{th}	Junction-ceramic Substrate (case glued to substrate)	SO14	90	°C/W
R _{th}	Junction-ceramic Substrate (case glued to substrate, substrate temperature maintened constant) SO14		65	°C/W

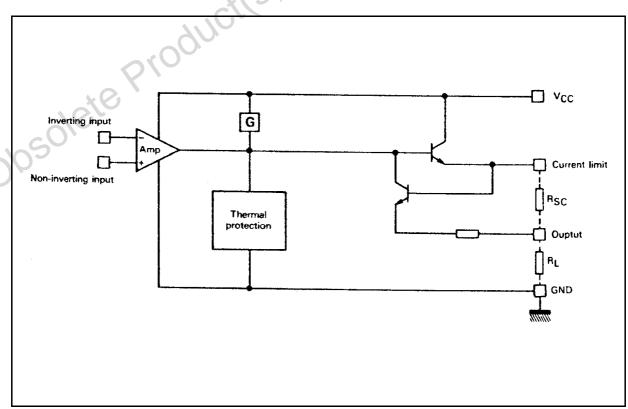
SCHEMATIC DIAGRAM



TEST CIRCUIT



SIMPLIFIED CIRCUIT



ELECTRICAL CHARACTERISTICS $T_j = -25$ to +85 °C, $V_{CC} = 8$ to 45 V, unless otherwise specified (note 1).

Symbol	Parameter	Min.	Тур.	Max.	Unit
V _{IO}	Input Offset Voltage - (note 2)	_	2	50	mV
I _{IB}	Input Bias Current	_	0.1	1.5	mA
Icc	Supply Current (V_{CC} = + 24 V , I_{O} = 0) High Level Low Level	_ _	4 2	6 4	mA mA
V _{I(max)}	Common-mode Input Voltage Range	2	_	V _{CC} -2	V
I _{SC}	Short-circuit Current Limit (T_{amb} = + 25 °C, V_{CC} = + 24) R_{SC} = 1.5 Ω TDE1747 R_{SC} = ∞	, _ _ _	480 35	50	mA mA
V _{CC} -V _O	Output Saturation Voltage (output high)	51	1.15 1.05	1.4 1.3	V
l _{OL}	Low Level Output Current $(V_O = 0, V_{CC} = + 24 \text{ V})$ $T_j = + 25 \text{ °C}$	-	0.01	10	μΑ

Notes:

Figure 1: Available Output Current vs. Limiting Resistor

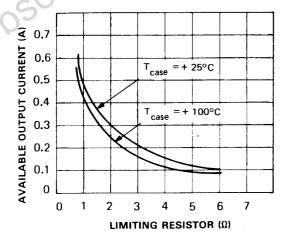
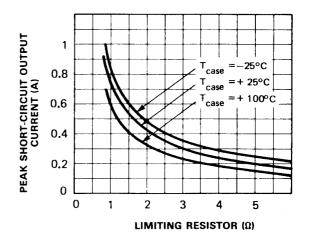


Figure 2: Peak Short-circuit Output Current vs. Limiting Resistor



¹⁾ For operating at high temperature, the TDE/TDF1747, must be derated based on a + 150 C maximum junction temperature and a junction-ambient thermal resistance of 120 °C/W for Minidip and 100 °C/W for the SO14.

²⁾ The offset voltage given is the maximum value of input voltage required to drive the output voltage within 2 V of the ground or the supply voltage.

Figure 3: Short-circuit Current vs. Case Temperature

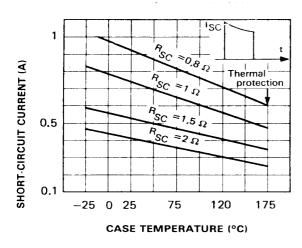


Figure 5: Output Current vs. Output Saturation Voltage

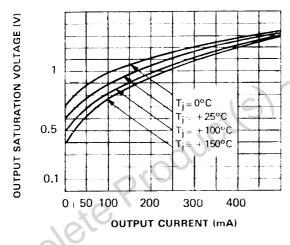


Figure 7: Supply Current vs. Junction Temperature

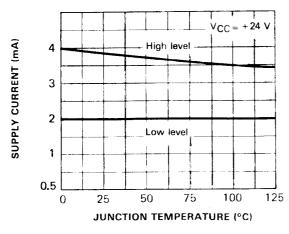


Figure 4: Minimum Limiting Resistor Value vs. Supply Voltage

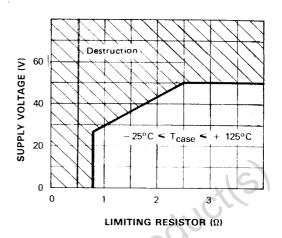


Figure 6: Supply Current vs. Supply Voltage

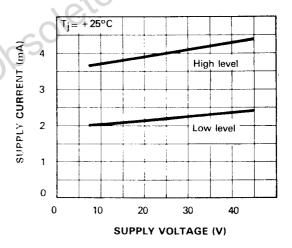
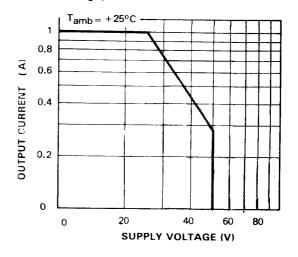
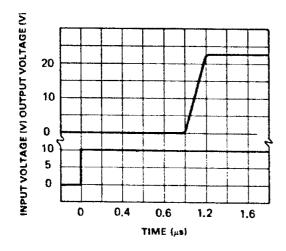


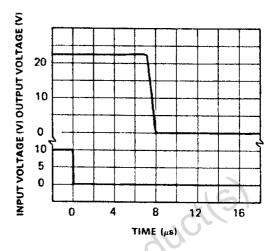
Figure 8: Safe Operating Area (non repetitive surge)



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Figure 9: Response Time





TYPICAL APPLICATIONS

Figure 10: Base Circuit

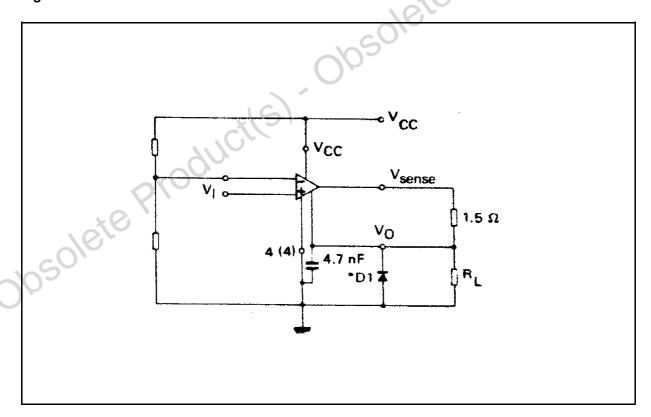


Figure 11: Output Current Extension (5A)

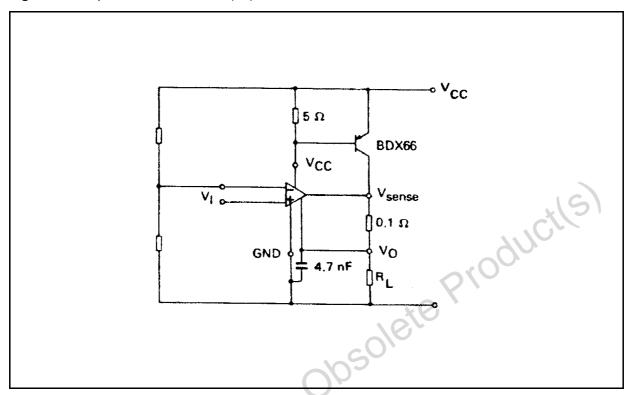
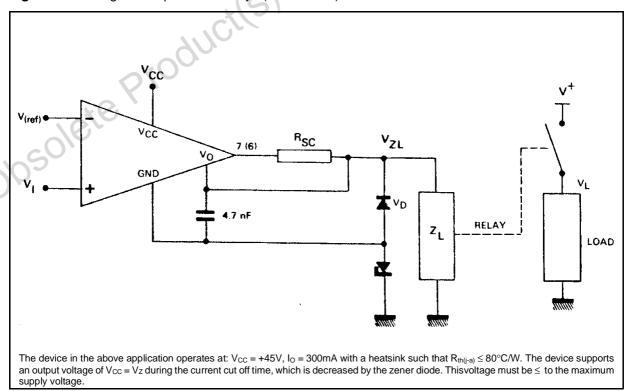
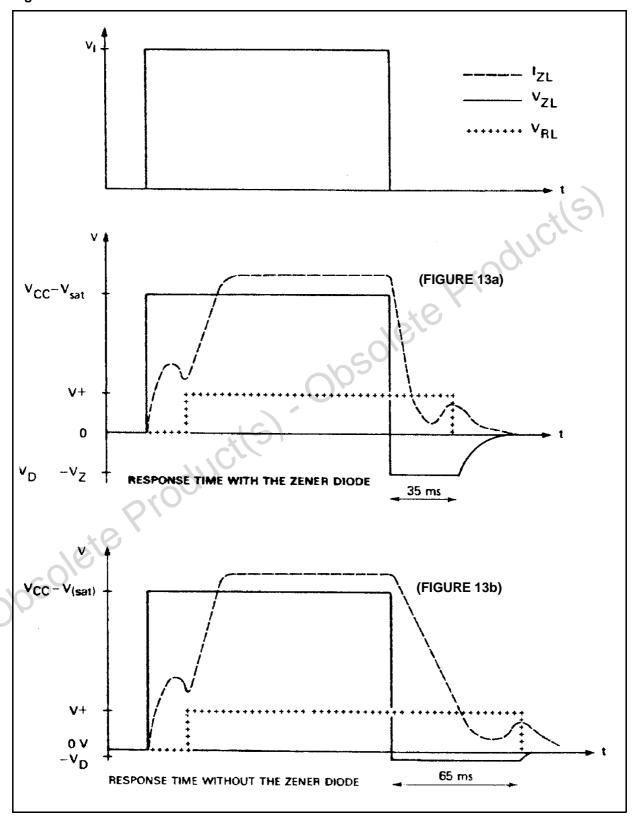


Figure 12: Driving Low Impedance Relays (Io = 300mA)



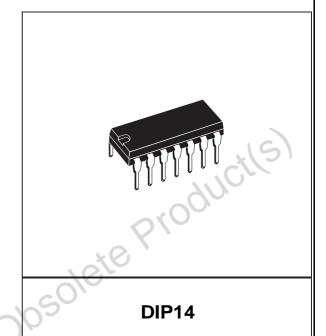
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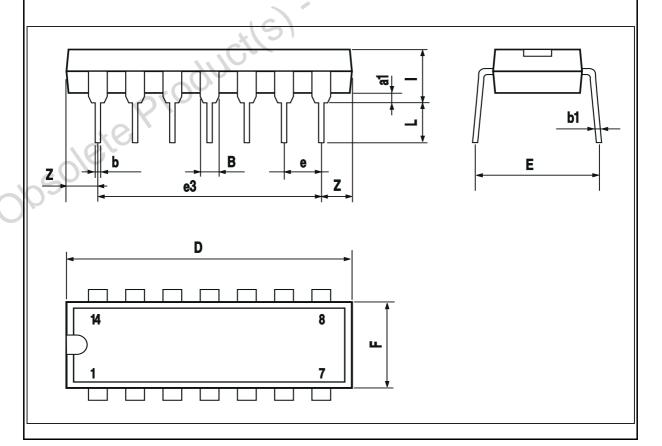
Figure 13: Waveforms



DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
a1	0.51			0.020		
В	1.39		1.65	0.055		0.065
b		0.5			0.020	
b1		0.25			0.010	
D			20			0.787
E		8.5			0.335	
е		2.54			0.100	
e3		15.24			0.600	
F			7.1			0.280
ı			5.1			0.201
L		3.3			0.130	
Z	1.27		2.54	0.050		0.100

OUTLINE AND MECHANICAL DATA

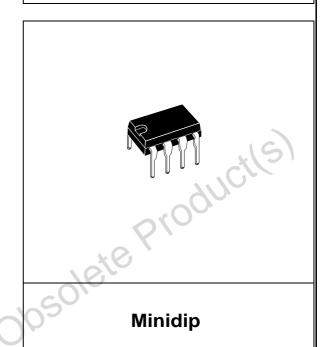


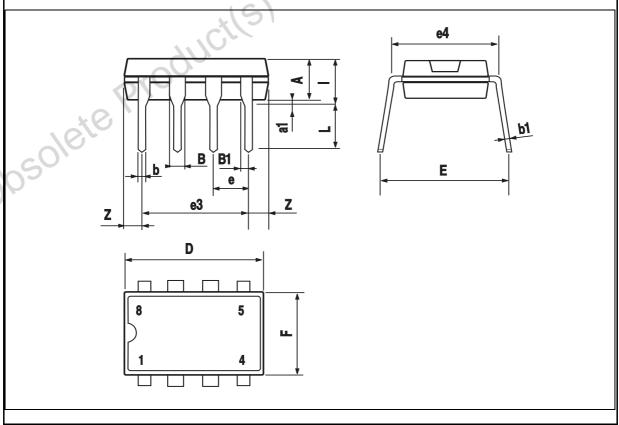


TDE1747 - TDF1747

DIM.	mm			inch			
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	
Α		3.32			0.131		
a1	0.51			0.020			
В	1.15		1.65	0.045		0.065	
b	0.356		0.55	0.014		0.022	
b1	0.204		0.304	0.008		0.012	
D			10.92			0.430	
E	7.95		9.75	0.313		0.384	
е		2.54			0.100		
e3		7.62			0.300		
e4		7.62			0.300		
F			6.6			0.260	
1			5.08			0.200	
L	3.18		3.81	0.125		0.150	
Z			1.52		4	0.060	

OUTLINE AND MECHANICAL DATA







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